Programmable Shunt Regulator

LM431SA, LM431SB, LM431SC

Description

The LM431SA / LM431SB / LM431SC are three-terminal the output adjustable regulators with thermal stability over operating temperature range. The output voltage can be set any value between V_{REF} (approximately 2.5 V) and 36 V with two external resistors. These devices have a typical dynamic output impedance of 0.2 Ω . Active output circuit provides a sharp turn-on characteristic, making these devices excellent replacement for zener diodes in many applications.

Features

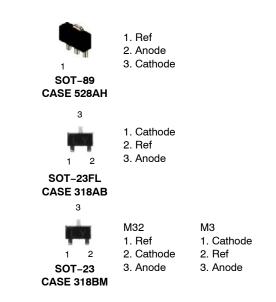
- Programmable Output Voltage to 36 V
- Low Dynamic Output Impedance: 0.2 Ω (Typical)
- Sink Current Capability: 1.0 to 100 mA
- Equivalent Full-Range Temperature Coefficient of 50 ppm/°C (Typical)
- Temperature Compensated for Operation Over Full Rated Operating Temperature Range
- Low Output Noise Voltage
- Fast Turn-on Response
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

ORDERING INFORMATION



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Product Number	Output Voltage Tolerance	Operating Temperature	Temperature Top Mark ⁽¹⁾ Package		Shipping [†]
LM431SACMFX	2%	–25 to +85°C	43A 🗆	SOT-23FL 3L	Tape and Reel
LM431SACM3X			43L ()	SOT-23 3L	
LM431SACM32X			43G ()	SOT-23 3L	
LM431SBCMLX	1%		43B	SOT-89 3L	
LM431SBCMFX			43B 🗆	SOT-23FL 3L	
LM431SBCM3X			43M ()	SOT-23 3L	
LM431SBCM32X			43H ()	SOT-23 3L	
LM431SCCMLX	0.5%		43C	SOT-89 3L	
LM431SCCMFX			43C 🗆	SOT-23FL 3L	
LM431SCCM3X			43N ()	SOT-23 3L	
LM431SCCM32X	7		43J ()	SOT-23 3L	
LM431SAIMFX	2%	–40 to +85°C	43AI	SOT-23FL 3L	
LM431SBIMFX	1%]	43BI	SOT-23FL 3L	
LM431SCIMFX	0.5%		43CI	SOT-23FL 3L	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

1. SOT-23 and SOT-23FL have basically four-character marking except LM431SAIMFX. (3 letters for device code + 1 letter for date code) SOT-23FL date code is composed of 1 digit numeric or alphabetic week code adding bar-type year code.

Block Diagram

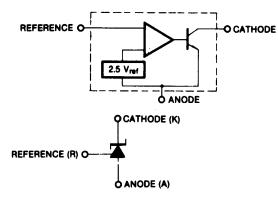


Figure 1. Block Diagram

ABSOLUTE MAXIMUM RATINGS (T_A = 25° C unless otherwise noted)

Symbol	Para	ameter	Value	Unit
V _{KA}	Cathode Voltage	37	V	
I _{KA}	Cathode current Range (Continuous)		-100 to +150	mA
I _{REF}	Reference Input Current Range	-0.05 to +10.00	mA	
$R_{\theta JA}$		ML Suffix Package (SOT-89)	220	°C/W
	Thermal Resistance Junction-Air ^(2, 3)	MF Suffix Package (SOT-23FL)	350	
		M32, M3 Suffix Package (SOT-23)	400	
PD	Power Dissipation ^(4, 5)	ML Suffix Package (SOT-89)	560	mW
		MF Suffix Package (SOT-23FL)	350	
		M32, M3 Suffix Package (SOT-23)	310	
TJ	Junction Temperature		150	°C
т	Operating Temperature Range	All products except LM431SAIMFX	-25 to +85	°C
T _{OPR}	Operating remperature mange	LM431SAIMFX, SBIMFX, SCIMFX	-40 to +85	
T _{STG}	Storage Temperature Range	·	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. Thermal resistance test board

Size: 1.6 mm x 76.2 mm x 114.3 mm (1S0P) JEDEC Standard: JESD51-3, JESD51-7.

3. Assume no ambient airflow.

4. $T_{JMAX} = 150^{\circ}$ C; ratings apply to ambient temperature at 25°C. 5. Power dissipation calculation: $P_D = (T_J - T_A) / R_{\theta JA}$.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V _{KA}	Cathode Voltage	V _{REF}	36	V
I _{KA}	Cathode Current	1	100	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

		Conditions		LM431SA		LM431SB			LM431SC				
Symbol	Parameter			Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
VREF	Reference Input Voltage	$V_{KA} = V_{REF}$, $I_{KA} = 10 \text{ mA}$		2.450	2.500	2.550	2.470	2.495	2.520	2.482	2.495	2.508	v
$\Delta V_{\text{BEF}} / \Delta T$	Deviation of Refer- ence Input Voltage Over- Tempera- ture	Vka = Vref,	SOT-89 SOT-23FL		4.5	17.0		4.5	17.0		4.5	17.0	mV
		$I_{KA} = 10 \text{ mA}$ TMIN \leq TA \leq TMAX	SOT-23		6.6	24		6.6	24		6.6	24	mV
ΔV _{REF} / ΔV _{KA}	Ratio of Change in Reference Input		ΔV _{KA} = 10 V–V _{REF}		-1.0	-2.7		-1.0	-2.7		-1.0	-2.7	
	Voltage to the Change in Cath- ode Voltage	I _{KA} =10 mA	ΔV _{KA} = 36 V – 10 V		-0.5	-2.0		-0.5	-2.0		-0.5	-2.0	mV/V
IREF	Reference Input Current	I_{KA} = 10 mA, R ₁ = 10 KΩ, R ₂ = ∞			1.5	4.0		1.5	4.0		1.5	4.0	μA
$\Delta I_{\text{REF}} / \Delta T$	Deviation of Refer- ence Input Current Over Full Temper- ature Range		SOT-89 SOT-23FL		0.4	1.2		0.4	1.2		0.4	1.2	μA
			SOT-23		0.8	2.0		0.8	2.0		0.8	2.0	μΑ
İKA(MIN)	Minimum Cathode Current for Regu- lation	Vka = Vref			0.45	1.00		0.45	1.00		0.45	1.00	mA
IKA(OFF)	Off –Stage Cath- ode Current	V _{KA} = 36 V, V _{REF} = 0			0.05	1.00		0.05	1.00		0.05	1.00	μA
Ζκα	Dynamic Imped- ance	Vĸa = VREF, I _{KA} = 1 to 100 mA, f ≥ 1.0 kHz			0.15	0.50		0.15	0.50		0.15	0.50	Ω

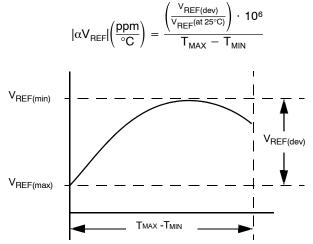
ELECTRICAL CHARACTERISTICS (Note 6, Values are at $T_A = 25^{\circ}C$ unless otherwise noted)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
6. LM431SAI, LM431SBI, LM431SCI: - T_{A(min)} = -40°C, T_{A(max)} = +85°C All other pins: - T_{A(min)} = -25°C, T_{A(max)} = +85°C

				LM431SAI			LM431SBI			LM431SCI			
Symbol	Parameter	Conditions			Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
V _{REF}	Reference Input Voltage	$V_{KA} = V_{REF}$, $I_{KA} = 10$ mA			2.500	2.550	2.470	2.495	2.520	2.482	2.495	2.508	V
V _{REF(dev)}	Deviation of Refer- ence Input Voltage Over-Temperature	$V_{KA} = V_{REF}$ $I_{KA} = 10$ mA, TMIN \leq TA \leq TMAX			5	20		5	20		5	20	mV
$\Delta V_{REF} / \Delta V_{KA}$	Ratio of Change in Reference Input Volt- age to Change in Cathode Voltage $I_{KA} = 10 \text{ mA}$		$\Delta V_{KA} = 10 \text{ V} - V_{REF}$		-1.0	-2.7		-1.0	-2.7		-1.0	-2.7	
		I _{KA} = 10 mA	ΔV _{KA} = 36 V – 10 V		-0.5	-2.0		-0.5	-2.0		-0.5	-2.0	mV/V
I _{REF}	Reference Input Current	$I_{KA} = 10 \text{ mA}, \text{ R}_1 = 10 \text{ K}\Omega, \text{ R}_2 = \infty$			1.5	4.0		1.5	4.0		1.5	4.0	μA
I _{REF(dev)}	Deviation of Refer- ence Input Current Over Full Temperature Range	I _{KA} = 10 mA, R Tmin ≤ Ta ≤ Tm		0.8	2.0		0.8	2.0		0.8	2.0	μΑ	
I _{KA(MIN)}	Minimum Cathode Current for Regulation	Vka = Vref		0.45	1.00		0.45	1.00		0.45	1.00	mA	
I _{KA(OFF)}	Off -Stage Cathode Current	V _{KA} = 36 V, V _{RI}		0.05	1.00		0.05	1.00		0.05	1.00	μA	
ZKA	Dynamic Impedance	V _{KA} = V _{REF} , I _{KA} f ≥ 1.0 kHz		0.15	0.50		0.15	0.50		0.15	0.50	Ω	

ELECTRICAL CHARACTERISTICS (Continued) (Notes 7 and 8, Values are at T_A = 25°C unless otherwise noted)

LM431SAI, LM431SBI, LM431SCI: - T_{A(min)} = -40°C, T_{A(max)} = +85°C All other pins: - T_{A(min)} = -25°C, T_{A(max)} = +85°C
 The deviation parameters V_{REF(dev)} and I_{REF(dev)}are defined as the differences between the maximum and minimum values obtained over the rated temperature range. The average full-range temperature coefficient of the reference input voltage, αV_{REF} is defined as:



where $T_{MAX} - T_{MIN}$ is the rated operating free-air temperature range of the device.

 αV_{REF} can be positive or negative, depending on whether minimum V_{REF} or maximum V_{REF}, respectively, occurs at the lower temperature.

Example:

V_{REF(dev)} = 4.5 mV, V_{REF} = 2500 mV at 25°C, $T_{MAX} - T_{MIN} = 125^{\circ}C$ for LM431SAI.

$$|\alpha V_{REF}| = \frac{\left(\frac{4.5 \text{ mV}}{2500 \text{ mV}}\right) \cdot 10^{6}}{125^{\circ}\text{C}} = 14.4 \text{ ppm/}^{\circ}\text{C}$$

Because minimum V_{REF} occurs at the lower temperature, the coefficient is positive.

TEST CIRCUITS

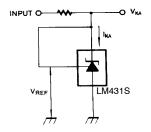


Figure 2. Test Circuit for $V_{KA} = V_{REF}$

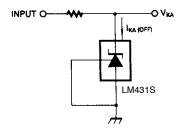


Figure 4. Test Circuit for IKA(OFF)

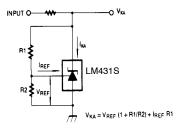


Figure 3. Test Circuit for $V_{KA} \ge V_{REF}$

TYPICAL APPLICATIONS

$$V_{O} = \left(1 + \frac{R_{1}}{R_{2}}\right) V_{\text{ref}}$$

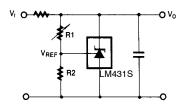


Figure 5. Shunt Regulator

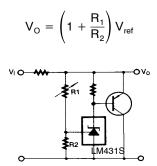


Figure 7. High Current Shunt Regulator

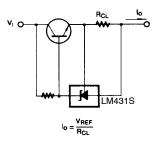
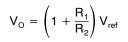


Figure 8. Current Limit or Current Source



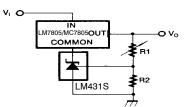


Figure 6. Output Control for Three–Terminal Fixed Regulator

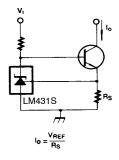


Figure 9. Constant-Current Sink

TYPICAL PERFORMANCE CHARACTERISTICS

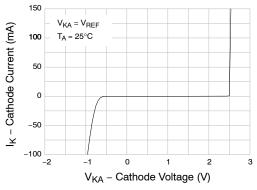


Figure 10. Cathode Current vs. Cathode Voltage

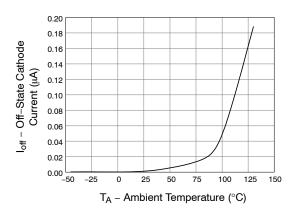


Figure 12. OFF–State Cathode Current vs. Ambient Temperature

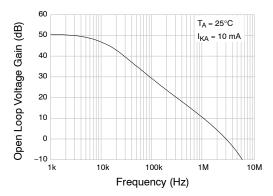


Figure 14. Frequency vs. Small Signal Voltage Amplification

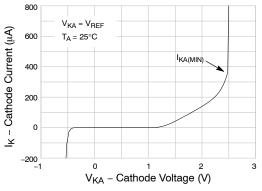


Figure 11. Cathode Current vs. Cathode Voltage

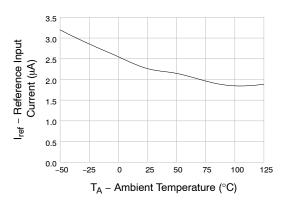


Figure 13. Reference Input Current vs. Ambient Temperature

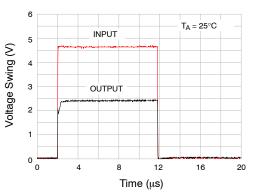


Figure 15. Pulse Response

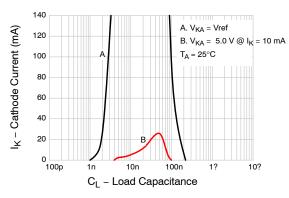


Figure 16. Stability Boundary Conditions

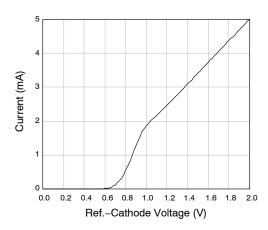


Figure 18. Reference–Cathode Diode Curve

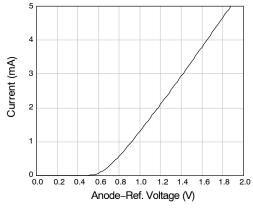


Figure 17. Anode-Reference Diode Curve

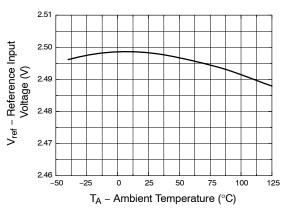


Figure 19. Reference Input Voltage vs. Ambient Temperature

SOT23-FL3L CASE 318AB ISSUE O DATE 11 DEC 2020 NDTES:
DIMENSIDNING AND TOLERANCING PER ASME Y14.5M, 2009.
CONTROLLING DIMENSION. MILLIMETERS
DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.127 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION.
DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM F.
DATUMEA AND B ARE TO BE DETERMINED AT DATUM F.
AI IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLAME TO THE LOWEST POINT ON THE PACKAGE BODY.
LEAD THICKNESS (C) AND LEAD WIDTH (b) INCLUDE PLATING THICKNESS. -A Г В 3 1 MILLIMETERS 2 NDM. DIM MIN. MAX. 1.15 Α PIN 1 b A1 0.00 0.10 INDICATOR ⊕|0,10M С Α В A2 0.90 1.00 1.10 b 0.30 0.50 TOP VIEW 0.127 REF С D 2.80 2.90 3.00 DETAIL A Ε 2.25 2.40 2.55 E1 1.20 1.30 1.40 ·A 1.90 BSC e L 0.30 ---A2 L1 0.55 REF L2 0.25 REF М 0* ----8* $\overline{}$ 3X 0.82 SIDE VIEW END VIEW 2.74 ₪ NDTE 5 A1 M٩ C 0.10 3X 0.56 1.90 2 С PITCH -11 RECOMMENDED MOUNTING FOOTPRINT DETAIL A For additional information on our Pb-Free the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D. GENERIC **MARKING DIAGRAM*** XXXM *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may XXX = Specific Device Code or may not be present. Some products may = Date Code Μ not follow the Generic Marking. Electronic versions are uncontrolled except when accessed directly from the Document Repository. DOCUMENT NUMBER: 98AON27911H Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

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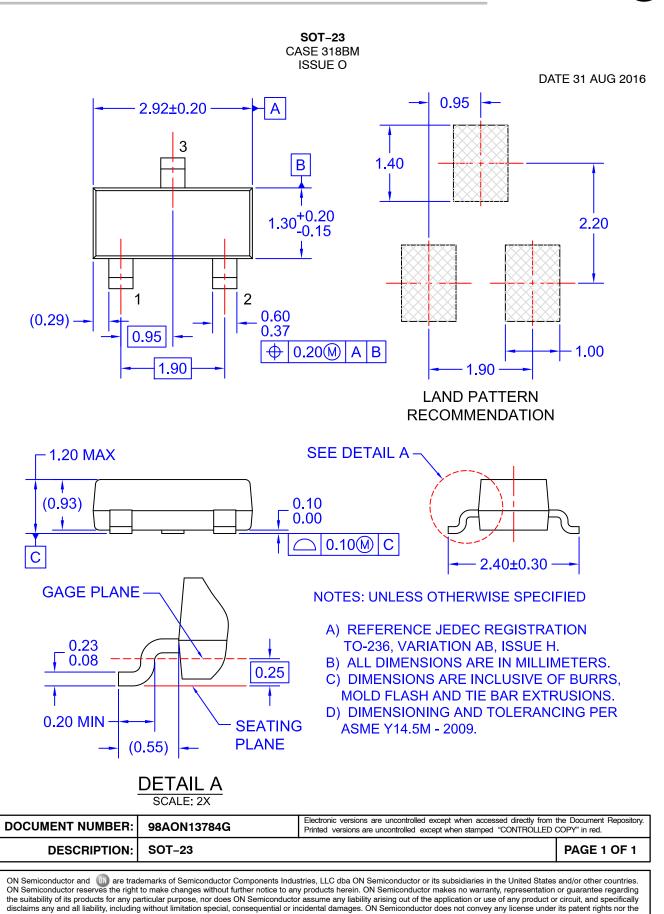
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PAGE 1 OF 1



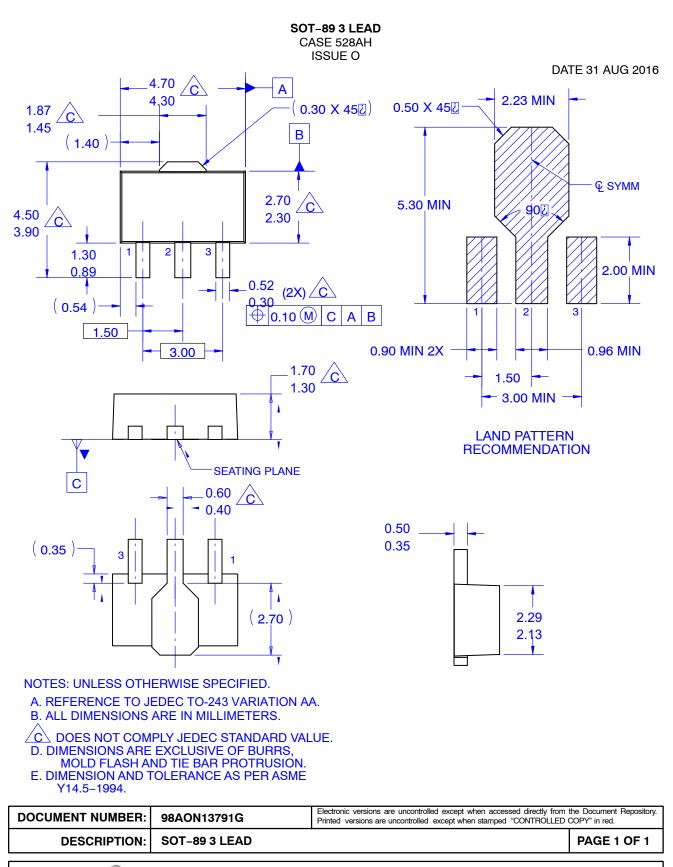




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